



TS331 TS332 TS334

Micropower low-voltage, rail-to-rail comparators

Datasheet — production data

Features

- Supply operation from 1.6 V to 5 V
- Low current consumption: 20 μ A
- Rail-to-rail inputs
- Wide temperature range: -40 °C to +125 °C
- Low output saturation voltage
- Low propagation delay: 210 ns
- Open-drain output
- ESD tolerance: 2 kV HBM/200 V MM
- SMD packages
- Automotive qualified

Applications

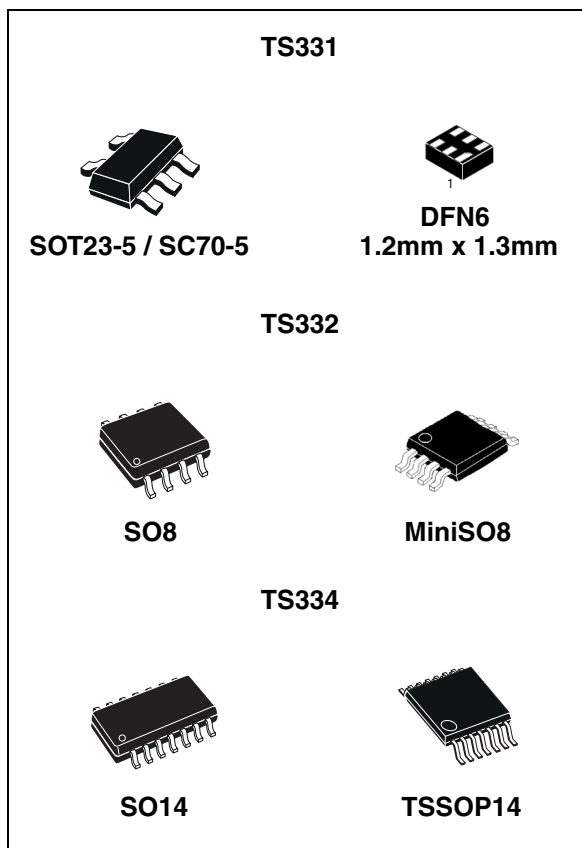
- Mobile phones
- Notebooks and PDAs
- Battery-supplied electronics
- General-purpose portable devices
- General-purpose low voltage applications

Description

The TS331, TS332 and TS334 are single, dual and quad micropower and low-voltage comparators. They can operate with a supply voltage ranging from 1.6 V to 5 V with a typical current consumption as low as 20 μ A. In addition, rail-to-rail inputs make them a perfect choice for low-voltage applications.

Their availability in tiny packages is a real advantage for space saving constraints.

The TS33x are specified for temperatures between -40 °C to +125 °C, making them ideal for a wide range of applications.

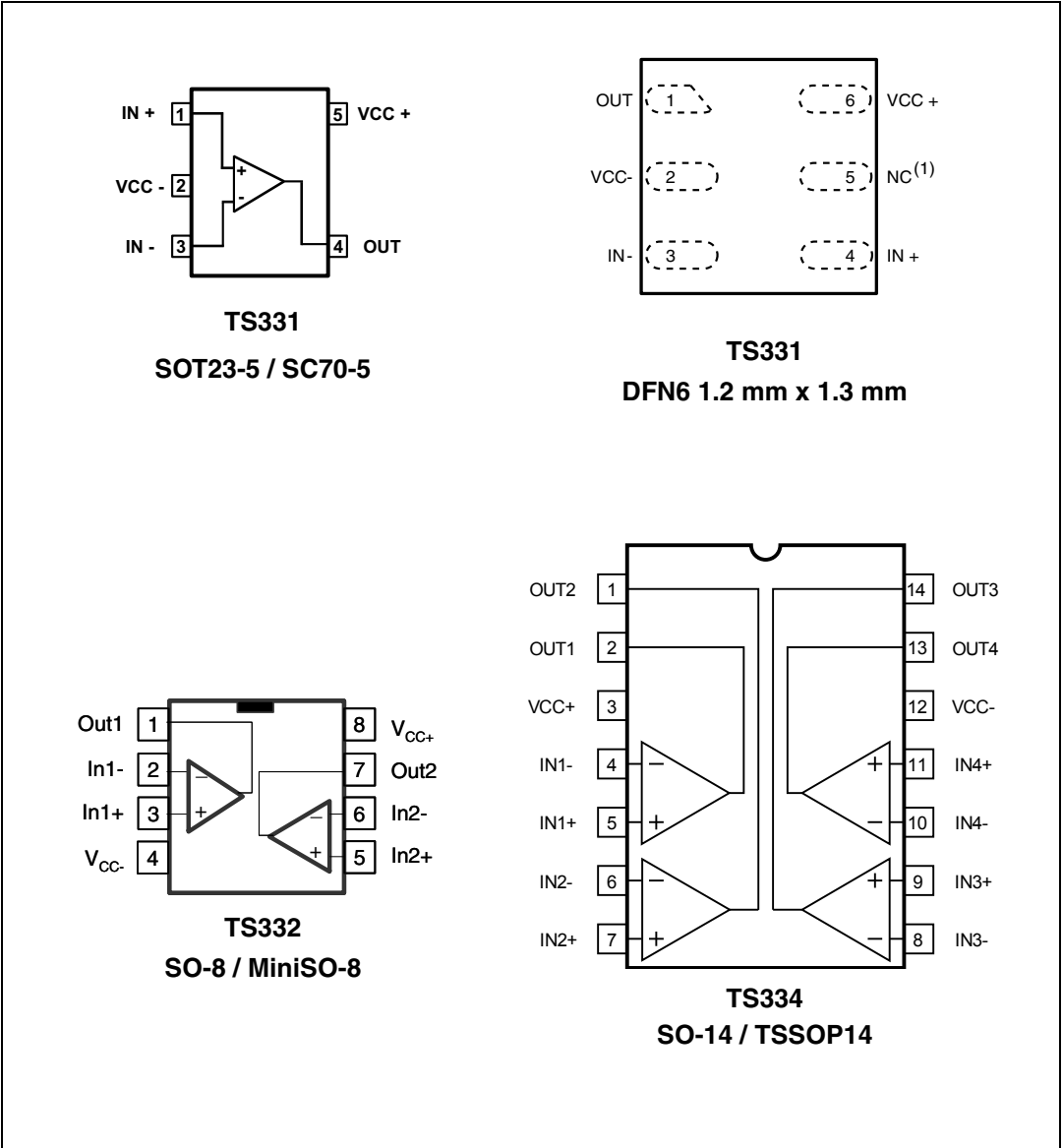


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1 Package pin connections

Figure 1. Pin connections for each package (top view)



1. NC = not connected

2 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ⁽¹⁾	5.5	V
V_{ID}	Differential input voltage	± 5.5	V
V_{IN}	Input voltage range	$(V_{CC-}) - 0.3$ to $(V_{CC+}) + 0.3$	V
V_{out}	Output voltage ⁽¹⁾	5.5	V
R_{thja}	Thermal resistance junction to ambient ⁽²⁾ DFN6 1.2 mm x 1.3 mm SC70-5 SOT23-5 SO8 MiniSO8 SO14 TSSOP14	40 205 250 125 190 105 100	$^{\circ}\text{C/W}$
R_{thjc}	Thermal resistance junction to case ⁽²⁾ SC70-5 SOT23-5 SO8 MiniSO8 SO14 TSSOP14	172 81 40 39 31 32	$^{\circ}\text{C/W}$
T_{stg}	Storage temperature	-65 to +150	$^{\circ}\text{C}$
T_j	Junction temperature	150	$^{\circ}\text{C}$
T_{LEAD}	Lead temperature (soldering 10 seconds)	260	$^{\circ}\text{C}$
ESD	Human body model (HBM) ⁽³⁾	2000	V
	Machine model (MM) ⁽⁴⁾	200	
	Charged device model (CDM) ⁽⁵⁾	1500	
	Latch-up immunity	200	mA

1. All voltage values, except differential voltage, are referenced to V_{CC-} .

2. Short-circuits can cause excessive heating. These values are typical

3. According to JEDEC standard JESD22-A114F

4. According to JEDEC standard JESD22-A115A

5. According to ANSI/ESD STM5.3.1

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
T_{oper}	Operating temperature range	-40 to +125	°C
V_{CC}	Supply voltage (V_{CC+}) - (V_{CC-}) -40°C < T_{amb} < +125°C	1.6 to 5.0	V
V_{ICM}	Common mode input voltage range $T_{amb} = +25^{\circ}\text{C}$ -40°C < T_{amb} < +125°C	(V_{CC-}) - 0.2 to (V_{CC+}) + 0.2 (V_{CC-}) to (V_{CC+})	V

3 Electrical characteristics

Table 3. $V_{CC+} = +1.8\text{ V}$, $V_{CC-} = 0\text{ V}$, $T_{amb} = +25^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		0.5	5 6	mV
ΔV_{IO}	Input offset voltage drift	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		4.5		$\mu\text{V}/^{\circ}\text{C}$
I_{IB}	Input bias current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		25	40 100	nA
I_{IO}	Input offset current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 100	nA
I_{CC}	Supply current	No load, output low, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		20	26 30	μA
		No load, output high, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		22	29 33	
I_{OH}	Output current leakage	$V_{OUT} = V_{CC+}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 500	nA
V_{OL}	Output voltage low	$I_{SINK} = 1\text{ mA}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		24	30 50	mV
I_{SINK}	Output sink current	$V_{OUT} = 1.5\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	20 15	22		mA
CMRR	Common mode rejection ratio	$0 < V_{ICM} < 1.8\text{ V}$	50	68		dB
TP_{HL}	Propagation delay ⁽²⁾ High to low output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		300 210	310	ns
TP_{LH}	Propagation delay ⁽³⁾ Low to high output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		540 420	620	ns

1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: inverting input voltage (IN^{-}) = V_{ICM} and non-inverting input voltage (IN^{+}) moving from $V_{ICM} + 100\text{ mV}$ to $V_{ICM} - \text{overdrive}$.

3. TP_{LH} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: inverting input voltage (IN^{-}) = V_{ICM} and non-inverting input voltage (IN^{+}) moving from $V_{ICM} - 100\text{ mV}$ to $V_{ICM} + \text{overdrive}$.

Table 4. $V_{CC+} = +2.7\text{ V}$, $V_{CC-} = 0\text{ V}$, $T_{amb} = +25^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		0.5	5 6	mV
ΔV_{IO}	Input offset voltage drift	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		3.3		$\mu\text{V}/^{\circ}\text{C}$
I_{IB}	Input bias current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		25	40 100	nA
I_{IO}	Input offset current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 100	nA
I_{CC}	Supply current	No load, output low, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$ No load, output high, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		21 23	27 31 30 34	μA
I_{OH}	Output current leakage	$V_{OUT} = V_{CC+}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 500	nA
V_{OL}	Output voltage low	$I_{SINK} = 1\text{ mA}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		17	30 50	mV
I_{SINK}	Output sink current	$V_{OUT} = 1.5\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	40 30	47		mA
CMRR	Common mode rejection ratio	$0 < V_{ICM} < 2.7\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	54 53	74		dB
TP_{HL}	Propagation delay ⁽²⁾ High to low output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		320 220	320	ns
TP_{LH}	Propagation delay ⁽³⁾ Low to high output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		550 420	640	ns

1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: Inverting input voltage ($IN-$) = V_{ICM} and non-inverting input voltage ($IN+$) moving from $V_{ICM} + 100\text{ mV}$ to $V_{ICM} - \text{overdrive}$.

3. TP_{LH} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: Inverting input voltage ($IN-$) = V_{ICM} and non-inverting input voltage ($IN+$) moving from $V_{ICM} - 100\text{ mV}$ to $V_{ICM} + \text{overdrive}$.

Table 5. $V_{CC+} = +5\text{ V}$, $V_{CC-} = 0\text{ V}$, $T_{amb} = +25^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IO}	Input offset voltage	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		0.5	5 6	mV
ΔV_{IO}	Input offset voltage drift	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1.3		$\mu\text{V}/^{\circ}\text{C}$
I_{IB}	Input bias current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		30	40 100	nA
I_{IO}	Input offset current ⁽¹⁾	$-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 100	nA
I_{CC}	Supply current	No load, output low, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$ No load, output high, $V_{ICM} = 0\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		23 26	30 34 34 38	μA
I_{OH}	Output current leakage	$V_{OUT} = V_{CC+}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		1	10 600	nA
V_{OL}	Output voltage low	$I_{SINK} = 4\text{ mA}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$		48	60 80	mV
I_{SINK}	Output sink current	$V_{OUT} = 1.5\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	82 60	93		mA
A_V	Voltage gain		40	100		V/mV
CMRR	Common mode rejection ratio	$0 < V_{ICM} < 5\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	60 58	79		dB
SVR	Supply voltage rejection	$\Delta V_{CC} = 1.8\text{ to }5\text{ V}$ $-40^{\circ}\text{C} < T_{amb} < +125^{\circ}\text{C}$	56 56	75		dB
TP_{HL}	Propagation delay ⁽²⁾ High to low output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		380 270	430	ns
TP_{LH}	Propagation delay ⁽³⁾ Low to high output level	$V_{ICM} = 0\text{ V}$, $R_L = 5.1\text{ k}\Omega$, $C_L = 50\text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		570 450	720	ns

1. Maximum values include unavoidable inaccuracies of the industrial tests.

2. TP_{HL} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: Inverting input voltage (IN-) = V_{ICM} and non-inverting input voltage (IN+) moving from $V_{ICM} + 100\text{ mV}$ to $V_{ICM} - \text{overdrive}$.

3. TP_{LH} is measured when the output signal crosses a voltage level at 50% of V_{CC} with the following conditions: Inverting input voltage (IN-) = V_{ICM} and non-inverting input voltage (IN+) moving from $V_{ICM} - 100\text{ mV}$ to $V_{ICM} + \text{overdrive}$.

Figure 2. Supply current versus supply voltage with output high, $V_{ICM} = 0\text{ V}$

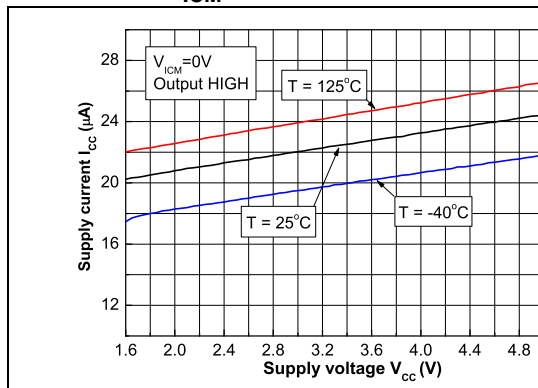


Figure 3. Supply current versus supply voltage with output high, $V_{ICM} = V_{CC}$

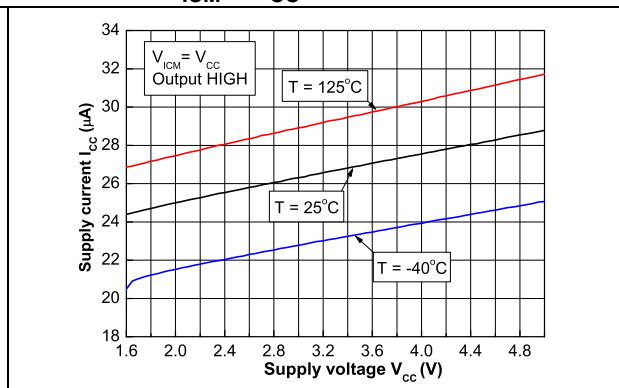


Figure 4. Supply current versus supply voltage with output low, $V_{ICM} = 0\text{ V}$

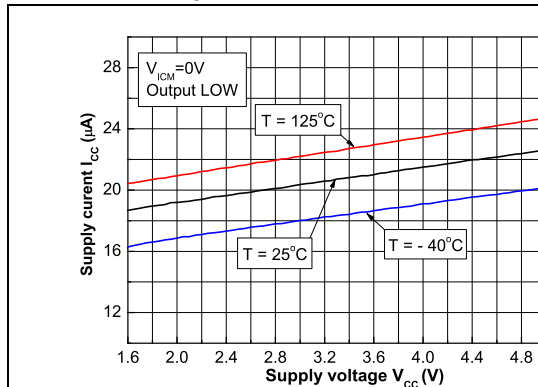


Figure 5. Supply current versus supply voltage with output low, $V_{ICM} = V_{CC}$

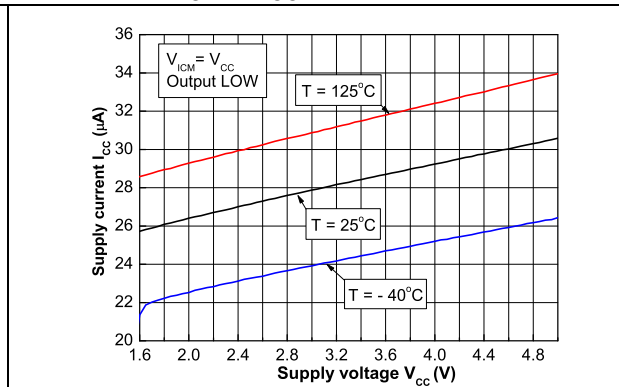


Figure 6. Supply current versus temperature **Figure 7. Input bias current versus input common-mode voltage**

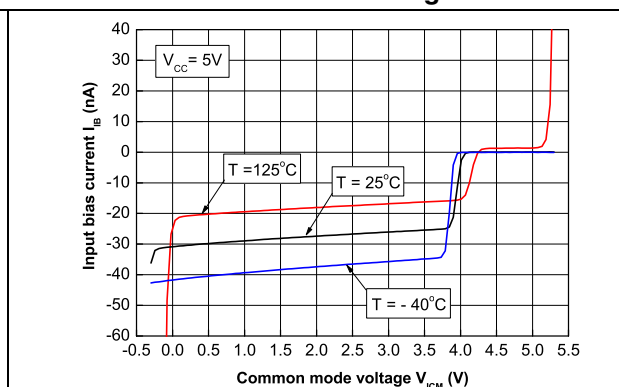
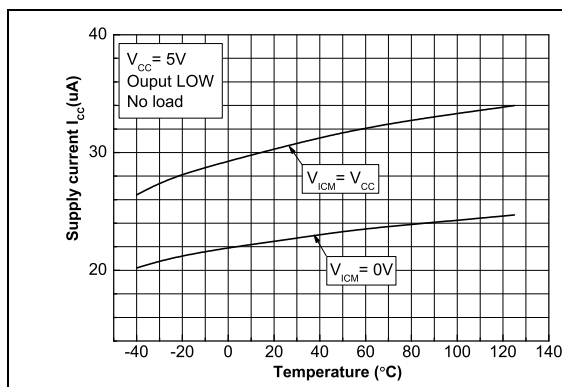


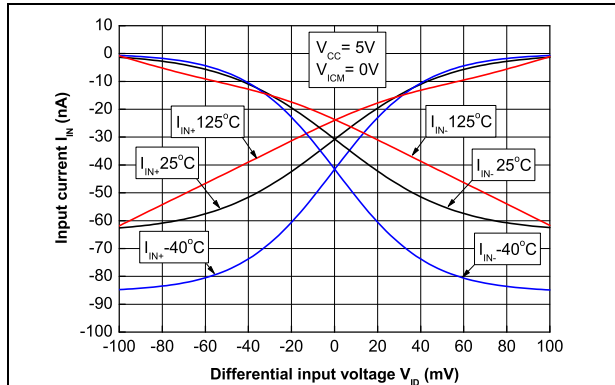
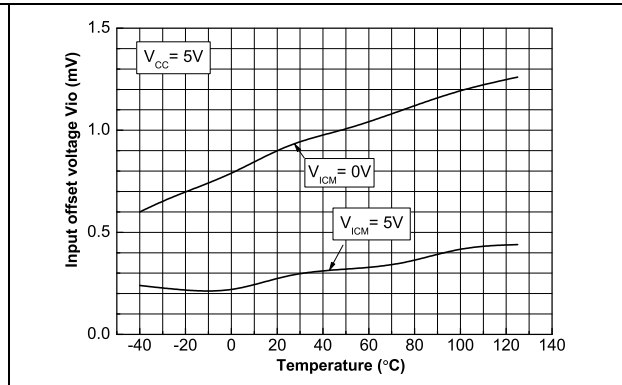
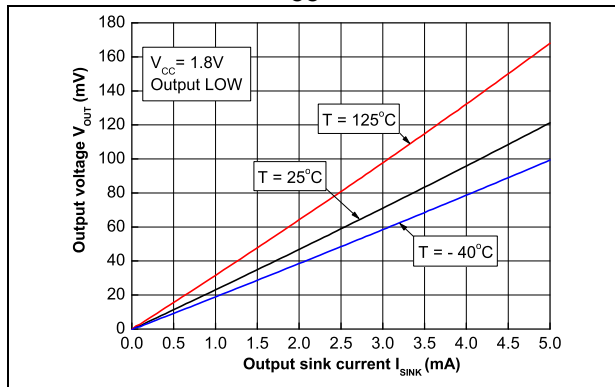
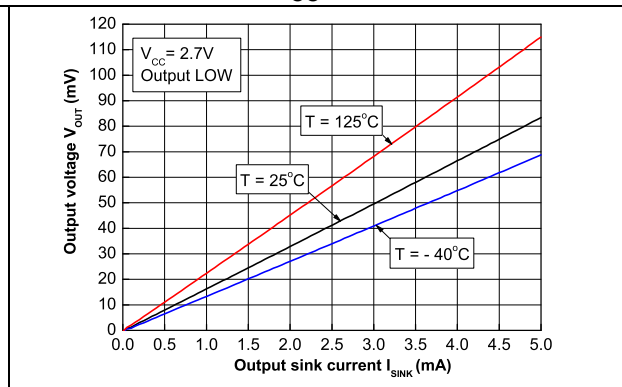
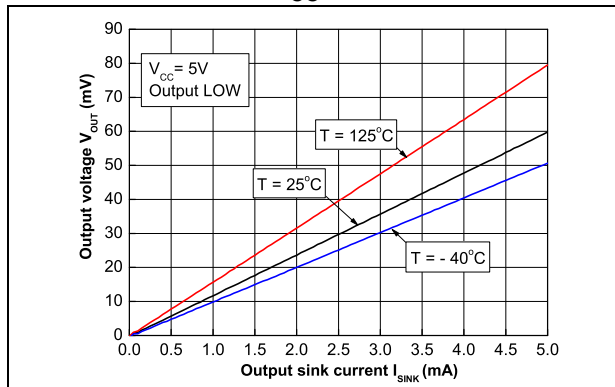
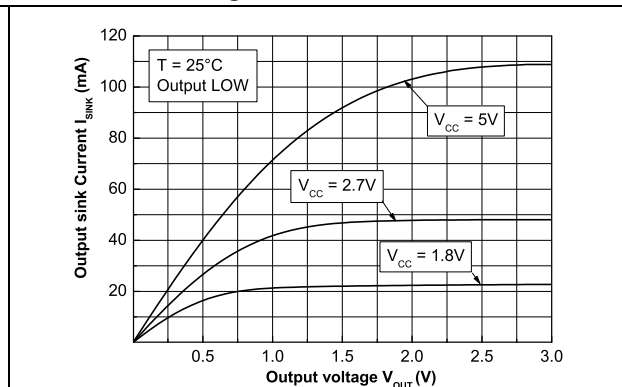
Figure 8. Input current versus differential input voltage**Figure 9. Input offset voltage versus temperature****Figure 10. Output voltage versus output sink current, $V_{CC} = 1.8\text{ V}$** **Figure 11. Output voltage versus output sink current, $V_{CC} = 2.7\text{ V}$** **Figure 12. Output voltage versus output sink current, $V_{CC} = 5\text{ V}$** **Figure 13. Output sink current versus output voltage**

Figure 14. Output voltage versus temperature **Figure 15. Propagation delay versus overdrive with negative transition, $V_{CC} = 1.8\text{ V}$**

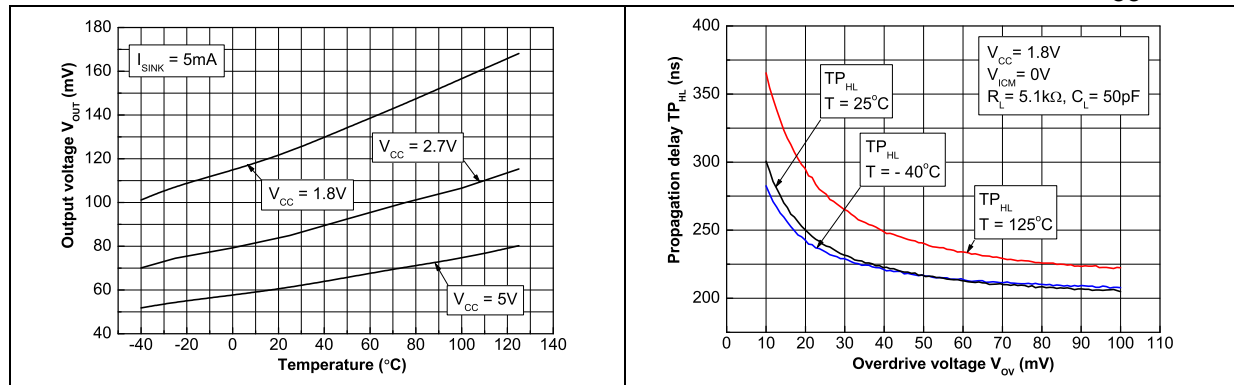


Figure 16. Propagation delay versus overdrive with positive transition, $V_{CC} = 1.8\text{ V}$ **Figure 17. Propagation delay versus common mode voltage, $V_{CC} = 1.8\text{ V}$**

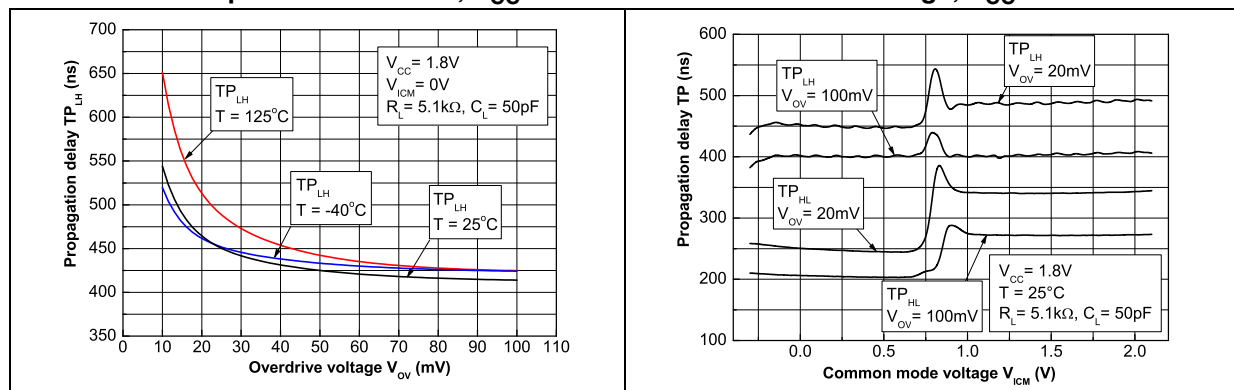


Figure 18. Propagation delay versus overdrive with negative transition, $V_{CC} = 2.7\text{ V}$ **Figure 19. Propagation delay versus overdrive with positive transition, $V_{CC} = 2.7\text{ V}$**

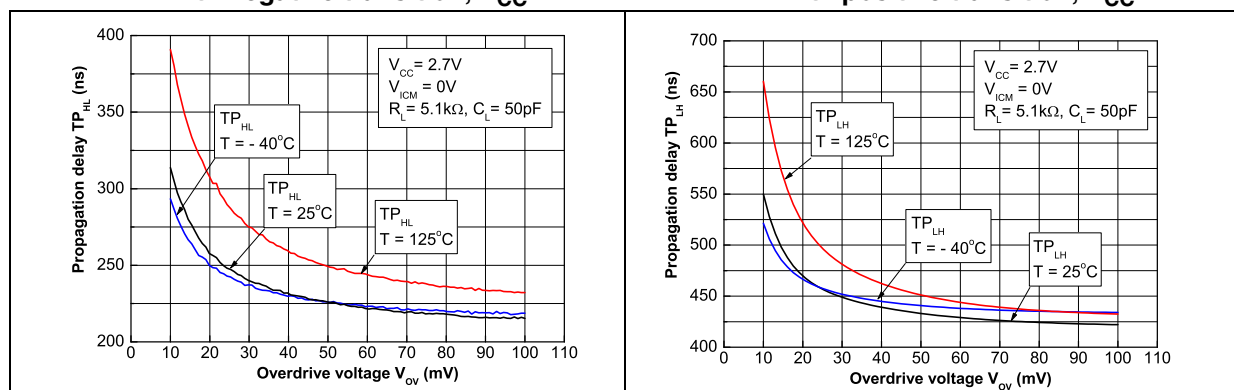
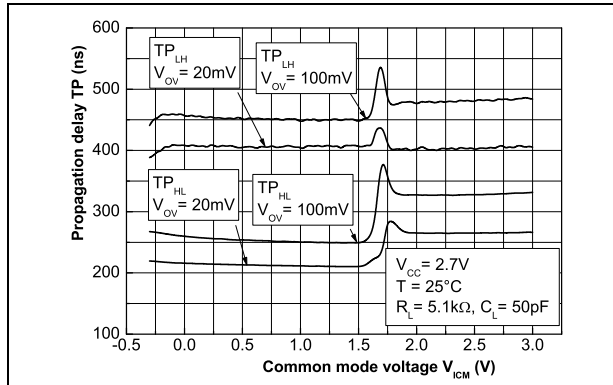
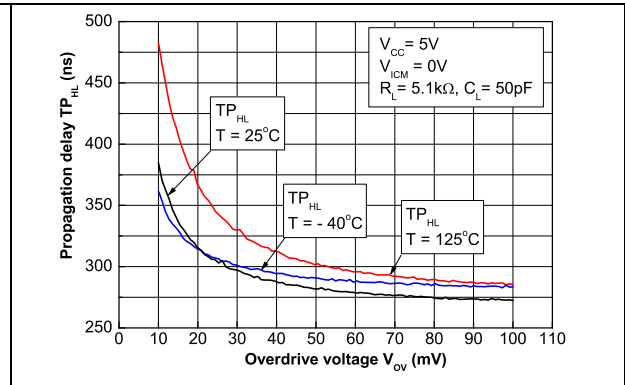
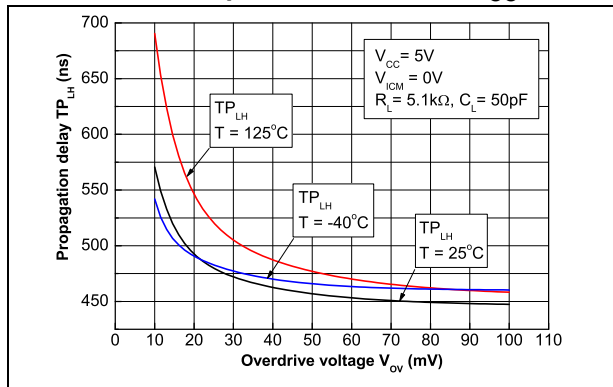
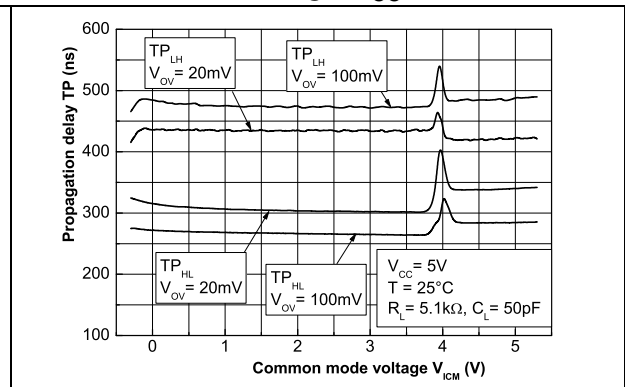
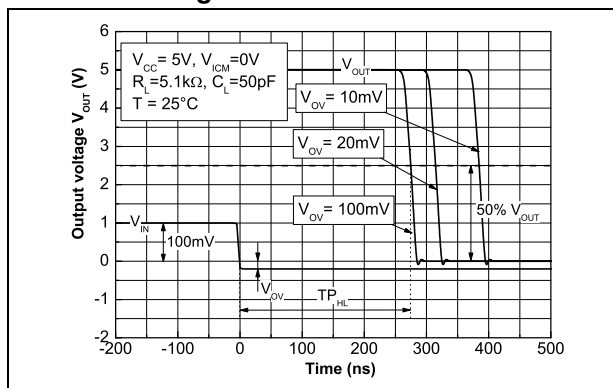
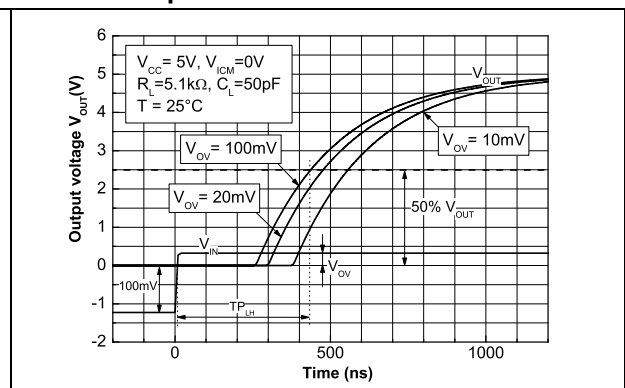


Figure 20. Propagation delay versus common mode voltage, $V_{CC} = 2.7\text{ V}$ **Figure 21. Propagation delay versus overdrive with negative transition, $V_{CC} = 5\text{ V}$** **Figure 22. Propagation delay versus overdrive with positive transition, $V_{CC} = 5\text{ V}$** **Figure 23. Propagation delay versus common mode voltage, $V_{CC} = 5\text{ V}$** **Figure 24. Propagation delay versus time with negative transition****Figure 25. Propagation delay versus time with positive transition**

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

4.1 SOT23-5 package

Figure 26. SOT23-5 package mechanical drawing

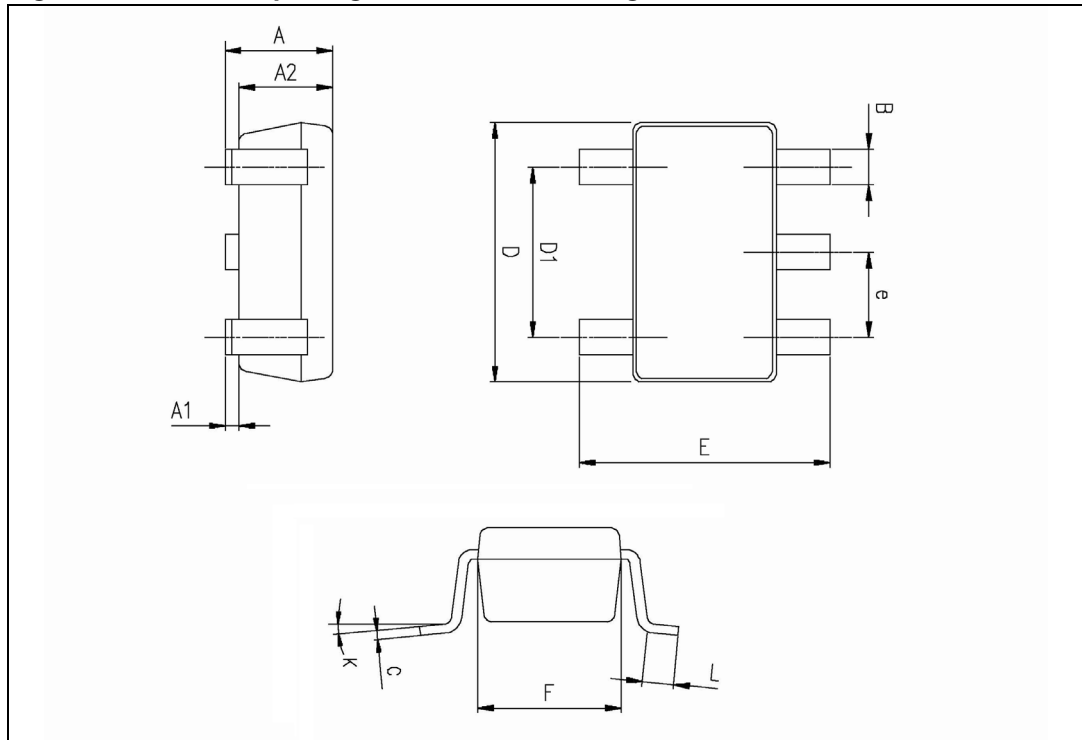


Table 6. SOT23-5 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90	1.20	1.45	0.035	0.047	0.057
A1			0.15			0.006
A2	0.90	1.05	1.30	0.035	0.041	0.051
B	0.35	0.40	0.50	0.013	0.015	0.019
C	0.09	0.15	0.20	0.003	0.006	0.008
D	2.80	2.90	3.00	0.110	0.114	0.118
D1		1.90			0.075	
e		0.95			0.037	
E	2.60	2.80	3.00	0.102	0.110	0.118
F	1.50	1.60	1.75	0.059	0.063	0.069
L	0.10	0.35	0.60	0.004	0.013	0.023
K	0°		10°	0°		10°

1. Values in inches are rounded to three decimal digits.

4.2 SC70-5 (SOT323-5) package

Figure 27. SC70-5 (SOT323-5) package mechanical drawing

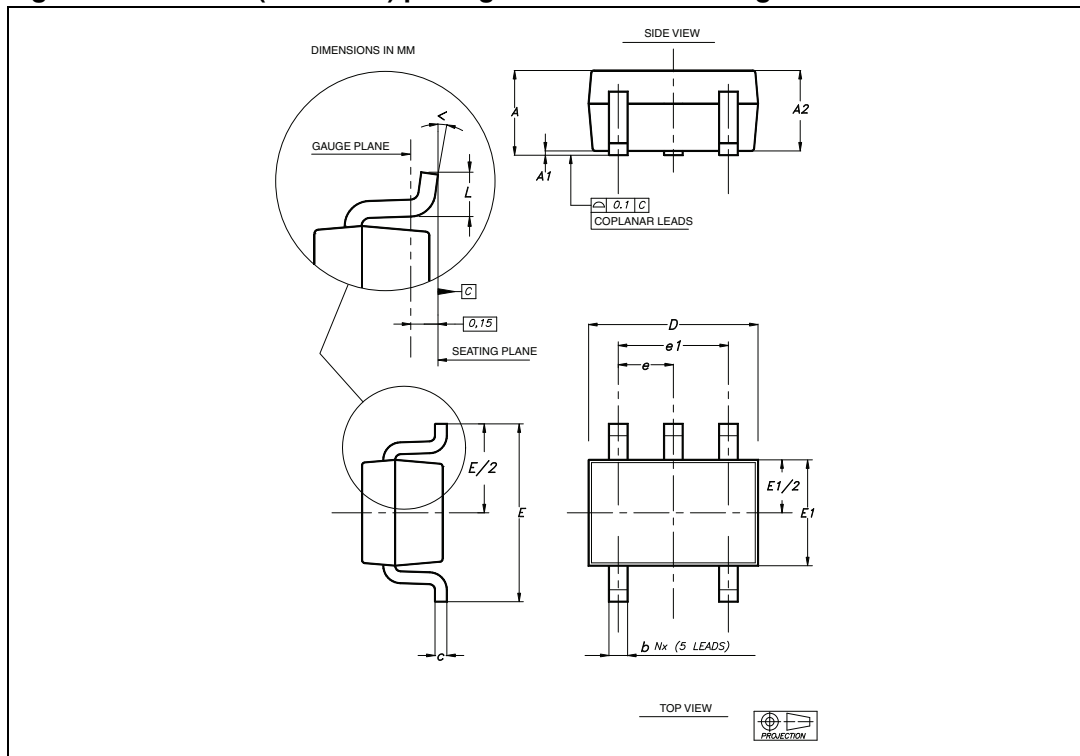


Table 7. SC70-5 (or SOT323-5) package mechanical data

Ref	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.80		1.10	0.315		0.043
A1			0.10			0.004
A2	0.80	0.90	1.00	0.315	0.035	0.039
b	0.15		0.30	0.006		0.012
c	0.10		0.22	0.004		0.009
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E1	1.15	1.25	1.35	0.045	0.049	0.053
e		0.65			0.025	
e1		1.30			0.051	
L	0.26	0.36	0.46	0.010	0.014	0.018
<	0°		8°	0°		8°

1. Values in inches are rounded to three decimal digits.

4.3 DFN6 package

Figure 28. DFN6 package mechanical drawing

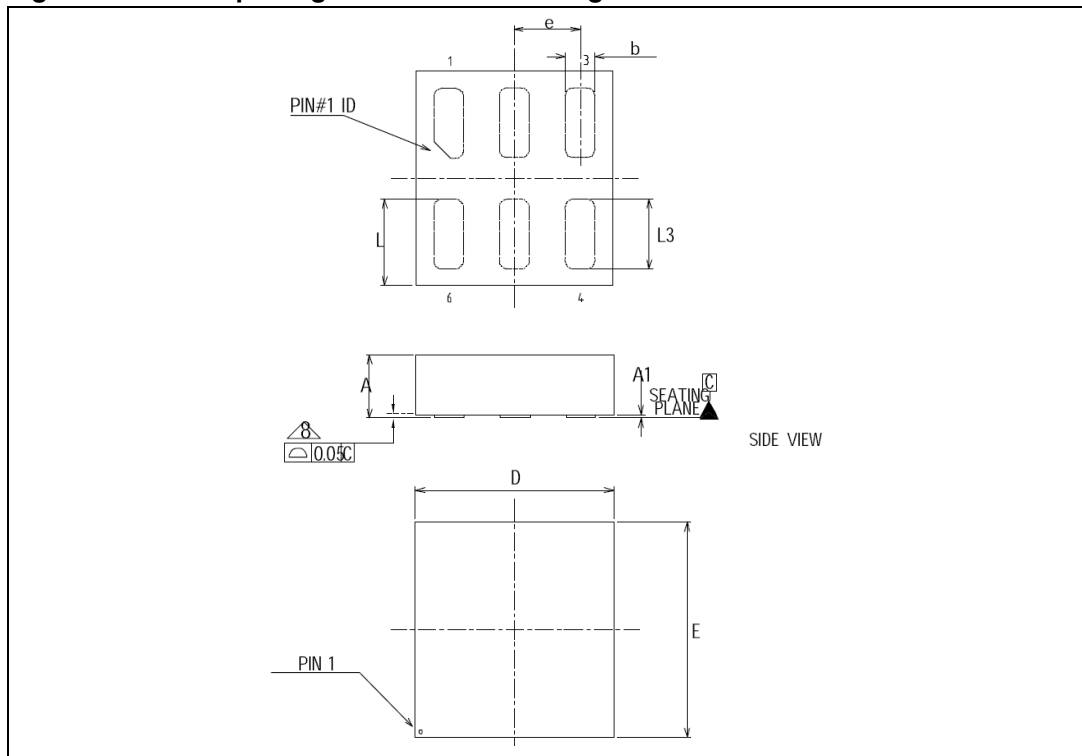


Table 8. DFN6 package mechanical data

Ref	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.15	0.18	0.25	0.006	0.007	0.002
c		0.05			0.002	
D		1.20			0.047	
E		1.30			0.051	
e		0.4			0.016	
L	0.475	0.525	0.575	0.019	0.021	0.023
L3	0.375	0.425	0.475	0.015	0.017	0.019

1. Values in inches are rounded to three decimal digits.

4.4 SO-8 package information

Figure 29. SO-8 package mechanical drawing

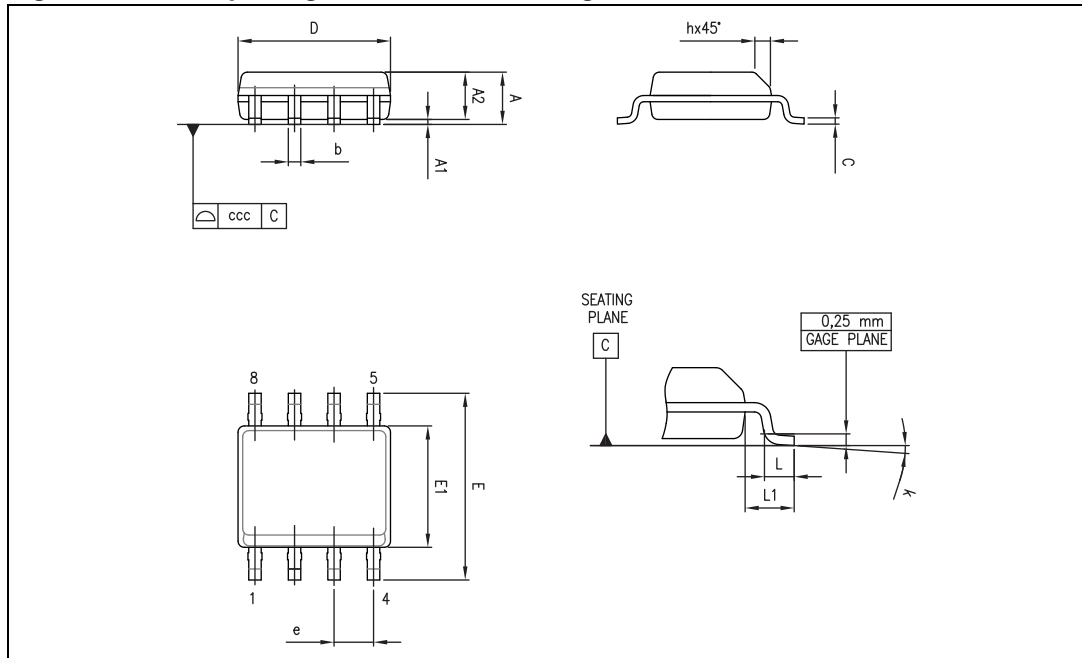


Table 9. SO-8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0		8°	1°		8°
ccc			0.10			0.004

1. Values in inches are rounded to three decimal digits.

4.5 MiniSO-8 package information

Figure 30. MiniSO-8 package mechanical drawing

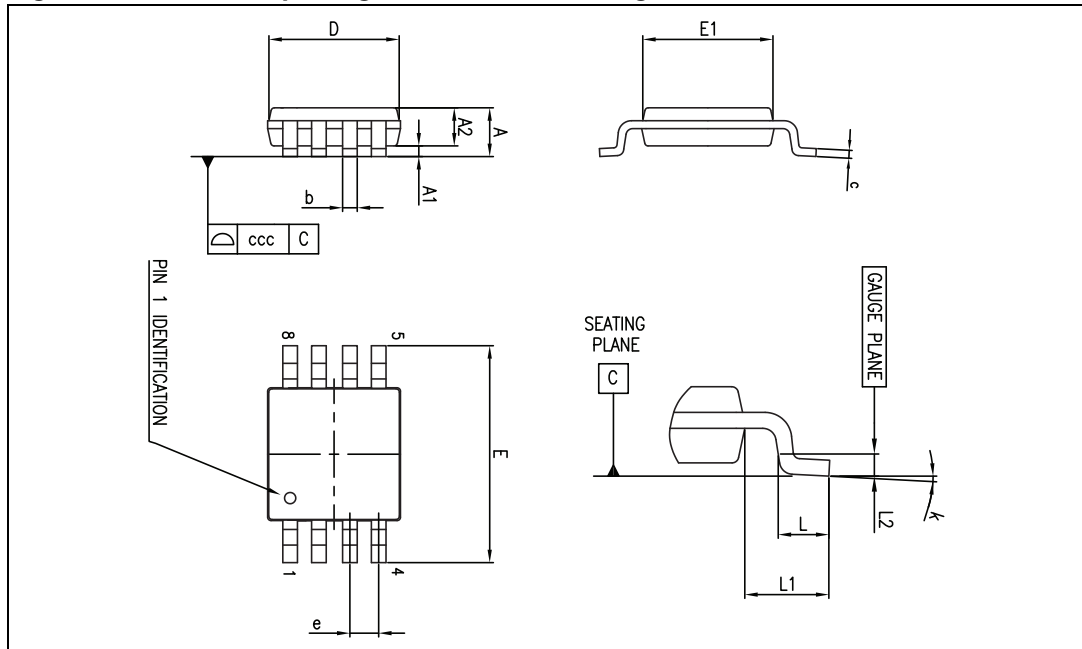


Table 10. MiniSO-8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0		0.15	0		0.006
A2	0.75	0.85	0.95	0.030	0.033	0.037
b	0.22		0.40	0.009		0.016
c	0.08		0.23	0.003		0.009
D	2.80	3.00	3.20	0.11	0.118	0.126
E	4.65	4.90	5.15	0.183	0.193	0.203
E1	2.80	3.00	3.10	0.11	0.118	0.122
e		0.65			0.026	
L	0.40	0.60	0.80	0.016	0.024	0.031
L1		0.95			0.037	
L2		0.25			0.010	
k	0°		8°	0°		8°
ccc			0.10			0.004

1. Values in inches are rounded to three decimal digits.

4.6 SO-14 package information

Figure 31. SO-14 package mechanical drawing

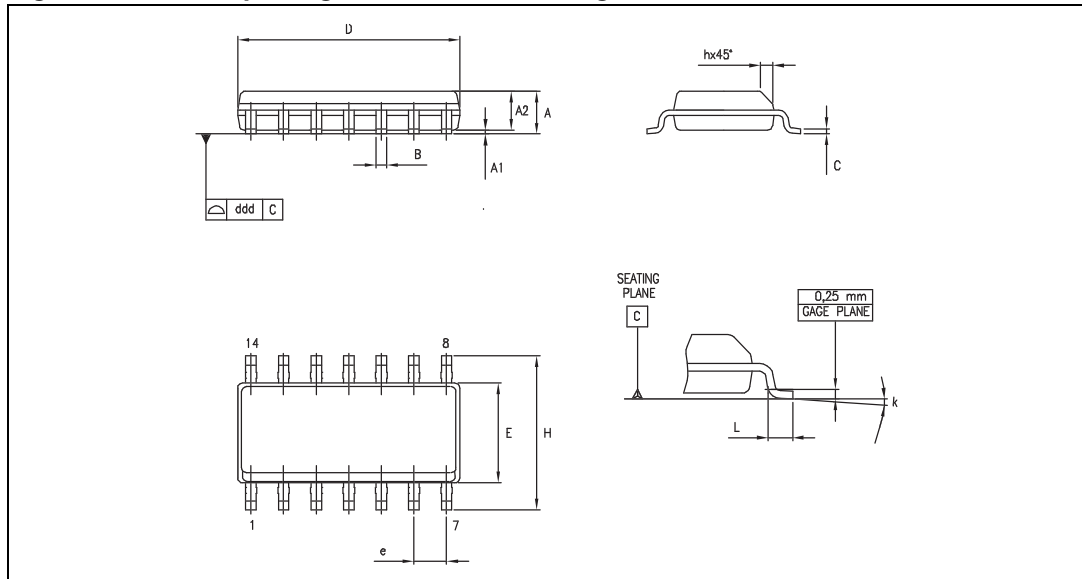


Table 11. SO-14 package mechanical data

Dimensions						
Ref.	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.35		1.75	0.050		0.068
A1	0.10		0.25	0.004		0.009
A2	1.10		1.65	0.040		0.060
B	0.33		0.51	0.010		0.020
C	0.19		0.25	0.007		0.009
D	8.55		8.75	0.330		0.340
E	3.80		4.0	0.150		0.150
e		1.27			0.05	
H	5.80		6.20	0.220		0.240
h	0.25		0.50	0.009		0.020
L	0.40		1.27	0.015		0.050
k	8° (max.)					
ddd			0.10			0.004

1. Values in inches are rounded to three decimal digits.

4.7 TSSOP14 package information

Figure 32. TSSOP14 package mechanical drawing

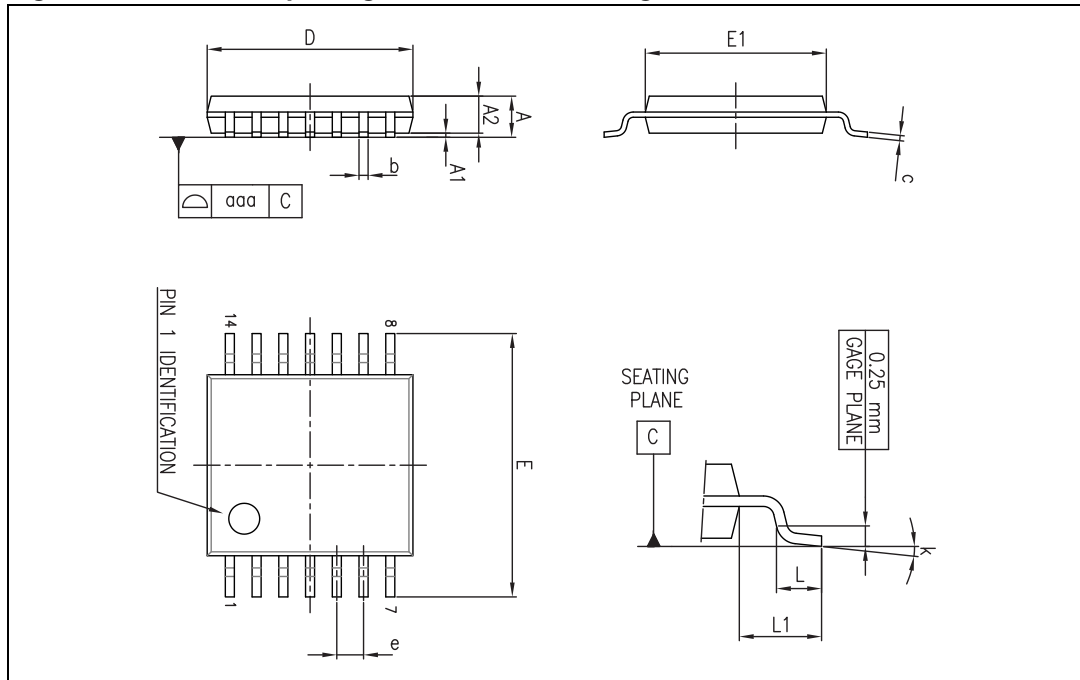


Table 12. TSSOP14 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.20			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.90	5.00	5.10	0.193	0.197	0.201
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.176
e		0.65			0.0256	
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1.00			0.039	
k	0°		8°	0°		8°
aaa			0.10			0.004

1. Values in inches are rounded to three decimal digits.

5 Ordering information

Table 13. Order codes

Order code	Temperature range	Package	Packaging	Marking
TS331IQT	-40 °C, +125 °C	DFN6 1.2x1.3mm	Tape & reel	K3
TS331ILT		SOT23-5		K506
TS331IYLT ⁽¹⁾		SOT23-5		K513
TS331ICT		SC70-5		K55
TS332IDT		SO8		332I
TS332IYDT ⁽¹⁾		SO8		332IY
TS332IST		MiniSO8		K507
TS334IDT		SO14		334I
TS334IPT		TSSOP14		334I
TS334IYPT ⁽¹⁾		TSSOP14		334IY

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.

6 Revision history

Table 14. Document revision history

Date	Revision	Changes
29-Mar-2010	1	Initial release.
01-Dec-2011	2	– Added TS332 and TS334 devices. – Added V_{out} parameter in Table 1: Absolute maximum ratings. – Removed note "The magnitude of input and output voltages must never exceed the supply rail ± 0.3 V." from Table 1. – Removed note "All values over the temperature range are guaranteed through correlation and simulation. No production tests have been performed at the temperature range limits." from Table 3, Table 4 and Table 5. – Removed "$V_{icm} = 0$ V" from Test conditions column in Table 3, Table 4 and Table 5. – Modified minimal I_{sink} value in Table 5.
29-Oct-2012	3	– Added DFN6 package for TS331 – Modified notes 3, 4, and 5 in Table 1 – Added Automotive grade order codes in Table 13

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